



## 30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

## **Product Summary**

BVDSS	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
-30V	$20m\Omega$ @ $V_{GS} = -10V$	-30A
-307	29mΩ @ V <sub>GS</sub> = -5V	-30A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Backlighting
- Power-management functions
- DC-DC converters

## **Features and Benefits**

- Low R<sub>DS(ON)</sub> ensures on state losses are minimized.
- Small form factor thermally efficient package enables higher density end products.
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product.
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

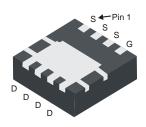
This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Package: PowerDI® 3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

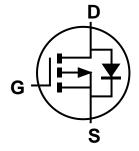
#### PowerDI3333-8







Top View



**Equivalent Circuit** 

# **Ordering Information** (Note 4)

Part Number	Package	Packing		
Fait Number	Раскауе	Qty.	Carrier	
DMP3036SFG-7	PowerDI3333-8	2,000	Tape & Reel	
DMP3036SFG-13	PowerDI3333-8	3,000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



# **Marking Information**

Site 1

PowerDI3333-8



P36 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

Site 2:

PowerDI3333-8



P36 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023)W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Kev

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	3	4	5	6	7	8	9	0	1	2
Week		1-26			27	<b>'-52</b>			53	
Code	A-Z			a-z			Z			
Internal Code	Sun	ı	Mon	Tue	W	ed	Thu	Fri		Sat
Code	Т		U	V	/	N	Х	Y		Z

## **Maximum Ratings** (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	-30	V	
Gate-Source Voltage		Vgss	±25	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	-8.7 -7.0	А
Continuous Drain Current (Note 7) $V_{GS} = -10V$ $T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$		lo	-30 -25	А
Continuous Drain Current (Note 6) $V_{GS} = -5V$ $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		lD	-7.2 -5.8	А
Continuous Drain Current (Note 7) V <sub>GS</sub> = -5V	ID	-30 -24	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-80	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	-3.6	Α	
Avalanche Current (Note 7) L=0.3mH	I <sub>AS</sub>	-17.5	Α	
Avalanche Energy (Note 7) L=0.3mH	E <sub>AS</sub>	64	mJ	

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Б.:	137	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	RθJA	65	°C/W
Total Power Dissipation (Note 6)		PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	ο	55	°C/W
t<10s		RθJA	26	°C/W
Thermal Resistance, Junction to Case (Note 7)	$R_{ heta JC}$	3.5	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).

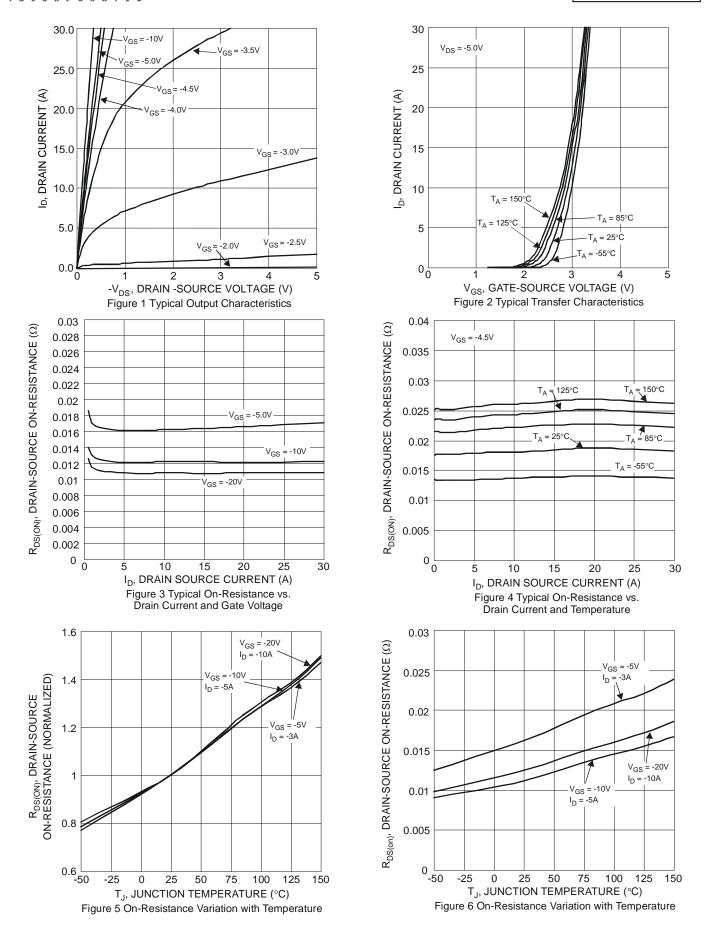


# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	-30	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	-	_	-1.0	μΑ	$V_{DS} = -30V$ , $V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	Vgs(TH)	-1.0	-2.0	-2.5	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
Static Drain-Source On-Resistance	D		13	20	mΩ	$V_{GS} = -10V, I_{D} = -8A$
Static Drain-Source On-Resistance	RDS(ON)	_	18.4	29	11122	$V_{GS} = -5V, I_{D} = -5A$
Diode Forward Voltage	$V_{SD}$	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		1931	_	pF	\
Output Capacitance	Coss		226	_	pF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	-	168	_	pF	1 = 1.01/11 12
Gate Resistance	Rg	_	10.9	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge V <sub>GS</sub> = -5V	Qg	_	8.8	_	nC	
Total Gate Charge V <sub>GS</sub> = -10V	Qg	_	16.5	_	nC	\/ 45\/ I- 40A
Gate-Source Charge	Qgs	_	2.6	_	nC	V <sub>DS</sub> = -15V, I <sub>D</sub> = -10A
Gate-Drain Charge	Qgd	_	3.6	_	nC	
Turn-On Delay Time	t <sub>D(ON)</sub>		8.2	_	ns	
Turn-On Rise Time	t <sub>R</sub>		14	_	ns	$V_{GS} = -10V, V_{DD} = -15V,$
Turn-Off Delay Time	tD(OFF)		65	_	ns	$R_{GEN} = 3\Omega$ , $I_D = -10A$
Turn-Off Fall Time	tr		31.6	_	ns	1
Reverse Recovery Time	trr		9.3	_	ns	
Reverse Recovery Charge	Q <sub>RR</sub>		12.2	_	nC	IF = -8A, di/dt = 500A/μs

8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing. Notes:







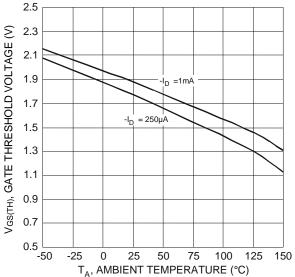


Figure 7 Gate Threshold Variation vs. Ambient Temperature

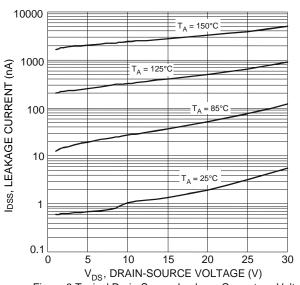
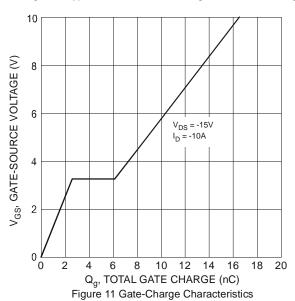
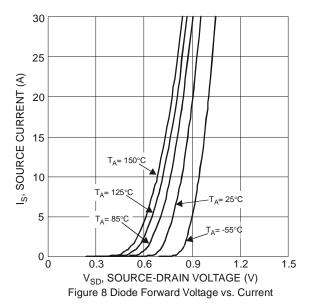
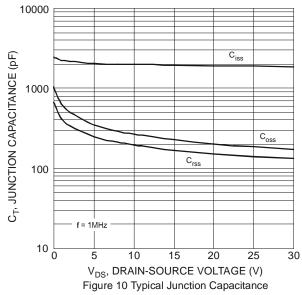
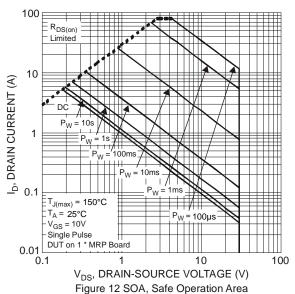


Figure 9 Typical Drain-Source Leakage Current vs. Voltage

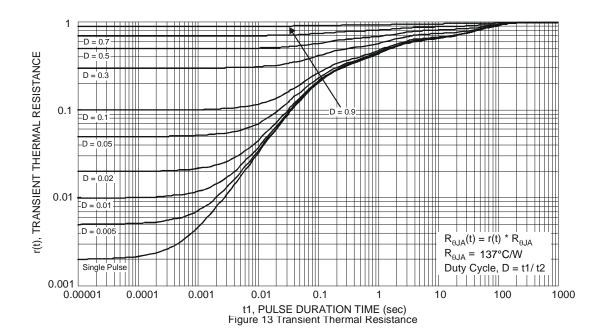










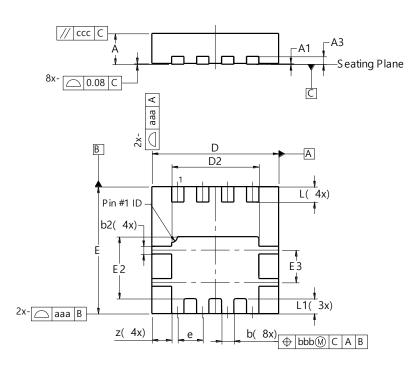




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI3333-8

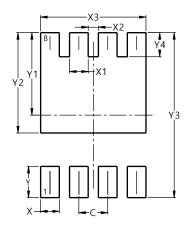


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	_	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
е	_	-	0.65		
L	0.35	0.45	0.40		
L1	1	I	0.39		
Z	_	_	0.515		
aaa	0.25				
bbb	0.10				
CCC	0.10				
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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